Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: |
|--|
| Glass |
| Overall Length: |
| 0.350 inches |
| Terminal Length: |
| 1.000 inches |
| Overall Diameter: |
| Between 0.155 inches and 0.205 inches |
| Mounting Method: |
| Terminal |
| Features Provided: |
| Burn in and electrostatic sensitive and hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 13.0 forward voltage, dc |
| Current Rating Per Characteristic: |
| 1.00 microamperes collector current, dc peak |
| Maximum Operating Tempurature Per Measurement Point: |
| 175.0 degrees celsius ambient air |
| Precious Material And Location: |
| Lead material silver |
| Precious Material: |
| Silver |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
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